# NSN 5961-01-020-4207

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-020-4207

Inclosure Material:

Ceramic

**Overall Length:** 

0.125 inches

## **Overall Diameter:**

0.200 inches

## **Mounting Facility Quantity:**

1

## **Mounting Method:**

Threaded stud

**Thread Size:** 

0.140 inches

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

30.0 breakdown voltage, collector-to-base, emitter open

## **Current Rating Per Characteristic:**

125.00 milliamperes all primaries

## **Power Rating Per Characteristic:**

2.5 watts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

## **Special Features:**

Junction pattern arrangement: npn

## **Thread Series Designator:**

Unc

## **Terminal Type And Quantity:**

1 threaded stud and 2 tab, solder lug

Shelf Life:

N/a

## Unit Of Measure:

---

## Demilitarization:

No

## Fiig:

A110a0